

### N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	$R_{DS(on)}$ (Ω) $I_{D}$ (A) <sup>e</sup>		Q <sub>g</sub> (Typ.)			
	0.028 at V <sub>GS</sub> = 4.5 V	6 <sup>a</sup>				
20	0.042 at V <sub>GS</sub> = 2.5 V	at $V_{GS} = 2.5 \text{ V}$ $6^{\text{a}}$ 8				
	0.050 at V <sub>GS</sub> = 1.8 V	5.6				

#### SOT-23 G 1 D 3 s 2 Top View

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET<sup>®</sup> Power MOSFET
- 100 % Rg Tested
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- DC/DC Converters
- Load Switch for Portable Applications

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20	v	
Gate-Source Voltage		V <sub>GS</sub>	± 12	V	
	T <sub>C</sub> = 25 °C		6 <sup>a</sup>		
Continuous Droin Current (T 150 °C)	T <sub>C</sub> = 70 °C	1 . [	5.1		
Continuous Drain Current ( $T_J = 150 \ ^\circ C$ )	T <sub>A</sub> = 25 °C		5 <sup>b, c</sup>		
	T <sub>A</sub> = 70 °C	1 –	4 <sup>b, c</sup>	A	
Pulsed Drain Current		I <sub>DM</sub>	20		
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C		1.75		
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	Is –	1.04 <sup>b, c</sup>		
	T <sub>C</sub> = 25 °C		2.1		
Maximum Power Dissinction	T <sub>C</sub> = 70 °C		1.3	w	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.25 <sup>b, c</sup>	vv	
	T <sub>A</sub> = 70 °C	1 –	0.8 <sup>b, c</sup>		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	
Soldering Recommendations (Peak Tempera		260			

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient <sup>b, d</sup>	$t \le 5 s$	R <sub>thJA</sub>	80	100	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	40	60	0/11		

Notes:

a. Package limited

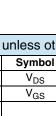
b. Surface Mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 125 °C/W.

e. Based on T\_C = 25 °C.

FREE



<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted							
Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
				T	-		
	$V_{GS} = 0 V$ , $I_{D} = 250 \mu A$	20			V		
$\Delta V_{DS}/T_{J}$	l <sub>p</sub> = 250 μA		25		mV/°C		
$\Delta V_{GS(th)}\!/T_J$			- 2.6		111 V/		
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	0.45		1.0	V		
I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA		
lana	$V_{DS} = 20 V, V_{GS} = 0 V$			1			
DSS	$V_{DS}$ = 20 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			10	μΑ		
I <sub>D(on)</sub>	$V_{DS} \leq 5$ V, $V_{GS}$ = 4.5 V	20			Α		
	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 5.0 \text{ A}$		0.028				
R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 4.7 \text{ A}$		0.042		Ω		
	$V_{GS} = 1.8 \text{ V}, \text{ I}_{D} = 4.3 \text{ A}$		0.050		1		
9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 5.0 A		24		S		
				<u> </u>	I		
C <sub>iss</sub>			865		pF		
	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		105				
	$V_{DS} = 10 \text{ V}. \text{ V}_{CS} = 5 \text{ V}. \text{ I}_{D} = 5.0 \text{ A}$		-	18	-		
Qg				-	nC		
Q <sub>as</sub>	$V_{DS} = 10 V$ , $V_{CS} = 4.5 V$ , $I_{D} = 5.0 A$		1.1				
			0.7				
•	f = 1 MHz	0.5	2.4	4.8	Ω		
			8	16			
	$V_{DD}$ = 10 V, $R_{L}$ = 2.2 $\Omega$		17		-		
-	$I_D \cong 4 \text{ A}, \text{ V}_{\text{GEN}} = 4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$						
. ,			-				
+			-	-	ns		
	$V_{DD} = 10 \text{ V}, \text{ R}_1 = 2.2 \Omega$		-	-			
	$I_D \cong 4 \text{ A}, V_{\text{GEN}} = 5 \text{ V}, \text{R}_g = 1 \Omega$						
	-						
· ·		I			I		
T . T	T <sub>C</sub> = 25 °C			1.75			
	<b>v</b>				A		
	$l_{s} = 4 A$ , $V_{cs} = 0 V$		0.75		v		
	······································		-		ns		
					nC		
	$I_F = 4 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^\circ\text{C}$		7	10			
Reverse Recovery Fall Time t <sub>a</sub> Reverse Recovery Rise Time t <sub>b</sub>					ns		
	$\begin{tabular}{ c                                   $	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A \\ \hline \Delta V_{GS(th)}/T_J & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A \\ \hline V_{GS}(th) & V_{DS} = 0 \ V, \ V_{GS} = 48 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 4.5 \ V \\ \hline V_{DS} = 10 \ V, \ V_{GS} = 1.8 \ V, \ I_D = 5.0 \ A \\ \hline \hline V_{DS} = 10 \ V, \ V_{GS} = 5 \ V, \ I_D = 5.0 \ A \\ \hline \hline V_{DS} = 10 \ V, \ V_{GS} = 5 \ V, \ I_D = 5.0 \ A \\ \hline \hline Q_{gs} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline Q_{gs} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline Q_{gg} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline Q_{gg} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline Q_{gg} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline Q_{gg} & I_D \ \equiv 4 \ A, \ V_{GEN} = 4.5 \ V, \ I_D = 1.0 \ A \\ \hline \hline P_{D} \ \equiv 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline I_D \ \equiv 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline I_D \ \equiv 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline I_D \ \equiv 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline I_T \ R_T \ V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline I_T \ R_T \ V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline \hline I_T \ R_T \ V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline \hline \hline V_T \ R_T \ V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline \hline \hline V_T \ R_T \ V_{SD} \ I_S \ = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline \hline \hline \hline \hline \hline \hline V_T \ V_T $	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions & Min. \\ \hline V_{DS} & V_{GS} = 0 V, I_D = 250 \ \mu A & 20 \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A & 0.45 \\ \hline I_D = 250 \ \mu A & 0.45 \\ \hline V_{GS}(th) & V_{DS} = V_{GS}, I_D = 250 \ \mu A & 0.45 \\ \hline I_{GSS} & V_{DS} = 0 V, V_{GS} = 48 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 0 \ V & V_{DS} = 20 \ V, V_{GS} = 15 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 5 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 5 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 4.5 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 4.5 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 4.5 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 4.5 \ V, I_D = 5.0 \ A & V_{DS} = 10 \ V, V_{GS} = 10 \ V, V_{GS} = 10 \ V, V_{DS} = 10 \ V \ V_{DS} = 10 \ V, V_{DS} = 10 \ V \ V_{DS} = 10 \ V, V_{DS} = 10 \ V \ V_{DS}$	$\begin{tabular}{ c c c c c } \hline Symbol & Test Conditions & Min. Typ. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 20 & 25 \\ \hline \Delta V_{GS(th)} & I_D = 250 \ \mu A & 0.45 & -2.6 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 0.45 & -2.6 \\ \hline V_{GS(th)} & V_{DS} = 0 \ V, \ V_{GS} = 4 \ V & 0.45 & -2.6 \\ \hline V_{GS}(th) & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & 0.5 & -2.6 & -2.6 \\ \hline V_{DS} & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & 0.5 & -2.6 & -2.6 \\ \hline V_{DS} & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & 0.5 & -2.6 & -2.6 & -2.6 \\ \hline V_{DS} & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{GS} = 0 \ V & 0.5 & -2.6 & -2.6 & -2.6 & -2.6 \\ \hline V_{DS} & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & 0.5 & -2.6 & -2.6 & -2.6 & -2.6 \\ \hline V_{DS} & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ I_D = 7.0 \ A & 0.042 & -2.6 & -2.6 & -2.6 & -2.6 \\ \hline V_{DS} & V_{DS} = 10 \ V, \ V_{GS} = 1 \ V, \ V_{DS} = 10 \ V, \ I_D = 5.0 \ A & -2.6 &$	$\begin{tabular}{ c c c c c c } \hline Symbol & Test Conditions & Min. Typ. Max. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 20 & 25 & 25 & 25 & 25 & 25 & 25 & 25$		

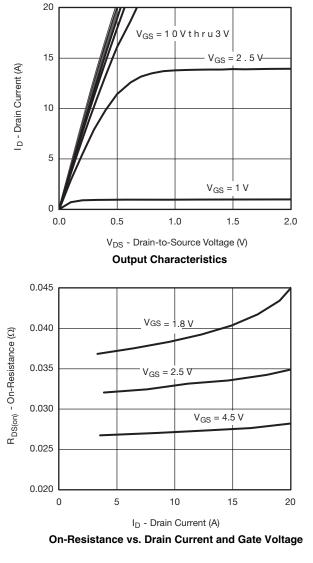
Notes:

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 % b. Guaranteed by design, not subject to production testing.

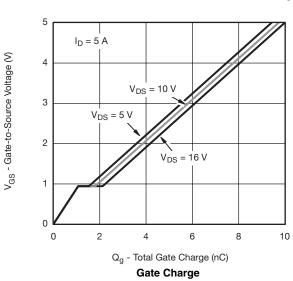
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

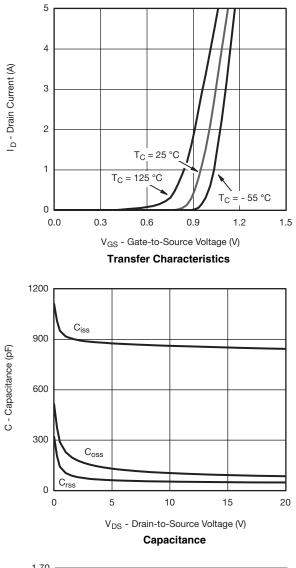
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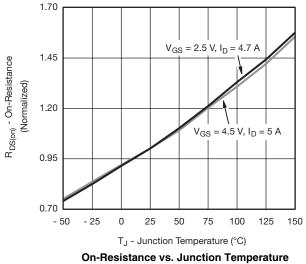




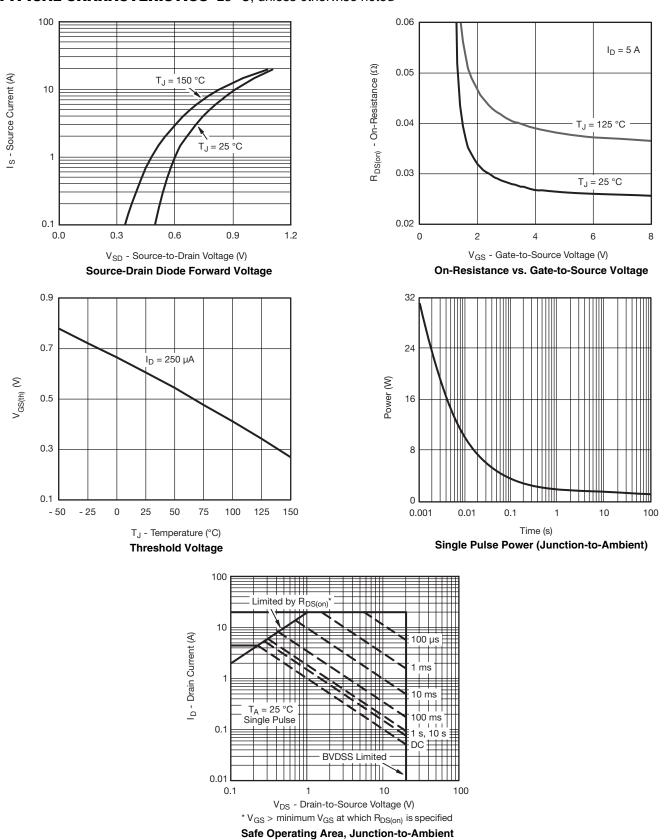
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







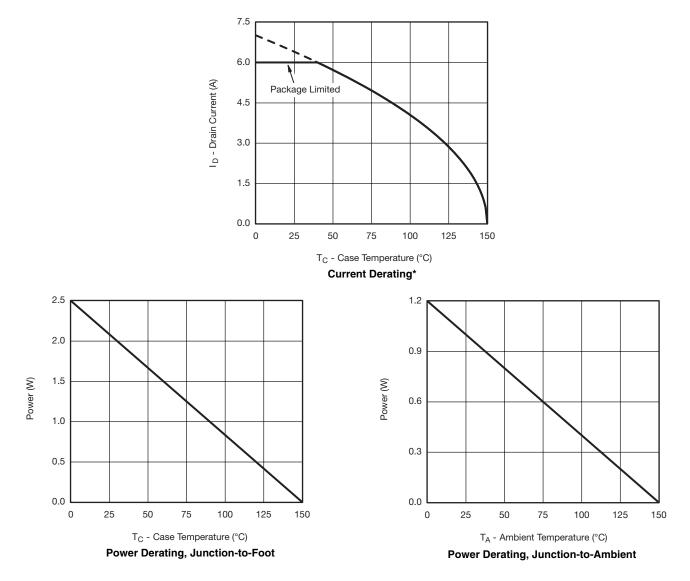




#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



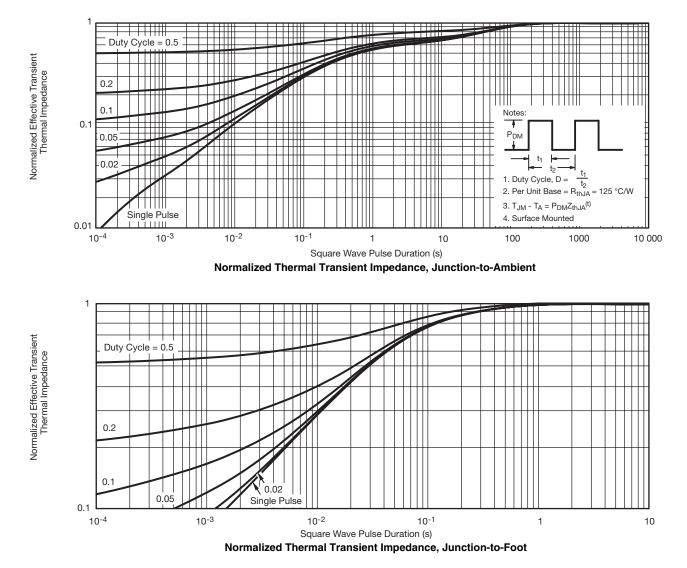
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



\* The power dissipation  $P_D$  is based on  $T_{J(max.)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



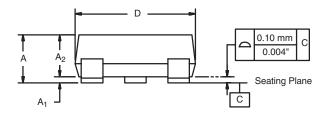






### SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	IETERS	INCHES		
	Min	Мах	Min	Мах	
Α	0.89	1.12	0.035	0.044	
A <sub>1</sub>	0.01	0.10	0.0004	0.004	
A <sub>2</sub>	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
C	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E <sub>1</sub>	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e <sub>1</sub>	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L <sub>1</sub>	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K, 09- DWG: 5479	Jul-01				



#### **RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads Dimensions in Inches/(mm)



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